



**Product data sheet** 

### 1. General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

### 2. Features and benefits

- Low reverse recovery current and low thermal resistance
- Reduces switching losses in associated MOSFET

### 3. Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- · Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

### 4. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating	· · · · · · · · · · · · · · · · · · ·					
$V_{RRM}$	repetitive peak reverse voltage		500			V	
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 129 °C; Fig. 1; Fig. 2	5		A		
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5 ; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 129 °C; square-wave pulse	10		A		
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse; <u>Fig. 3</u>		40			A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	ie 44			А	
Symbol	Parameter	Conditions	Min Typ Max		Max	Unit	
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.5	2	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	1.15	1.45	V
Dynamic	characteristics	· · · · · · · · · · · · · · · · · · ·		,			
t <sub>rr</sub>	reverse recovery time	$I_F = 5 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_i = 25 \text{ °C}; Fig. 6$		-	16	-	ns

## 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	А	anode	j O j	K <u>– – – –</u> A 001aaa020
mb	mb	mounting base; connected to cathode	C	001aaa020

## 6. Ordering information

Table 3. Ordering inform	nation				
Type number	ber Package				
	Name	Description	Version		
BYC5D-500	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59		

## 7. Marking

Table 4. Marking codes						
	Type number	Marking codes				
	BYC5D-500	BYC5D-500				

003aag306

a = 1.57

5

4

I<sub>F(AV)</sub> (A)

1.9 2.2

2.8

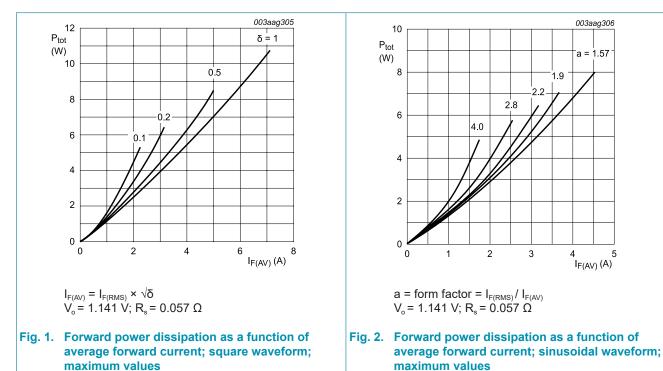
3

### 8. Limiting values

### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

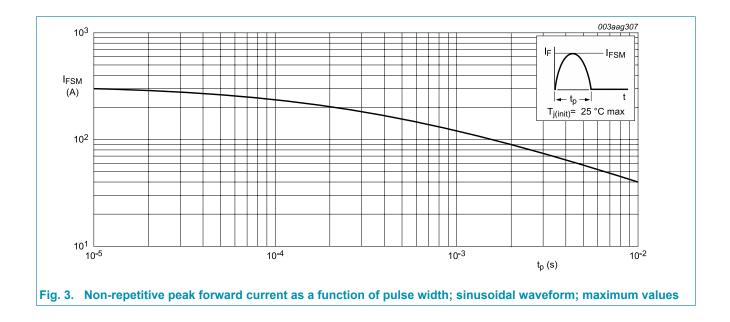
Symbol	Parameter	Conditions	Values	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		500	V
V <sub>RWM</sub>	crest working reverse voltage		500	V
V <sub>R</sub>	reverse voltage	DC	500	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 129 °C; Fig. 1; Fig. 2	5	A
I <sub>FRM</sub>	repetitive peak forward current	δ = 0.5; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 129 °C; square-wave pulse	10	A
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse; <u>Fig. 3</u>	40	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	44	A
T <sub>stg</sub>	storage temperature		-40 to 150	°C
T <sub>j</sub>	junction temperature		150	°C



maximum values

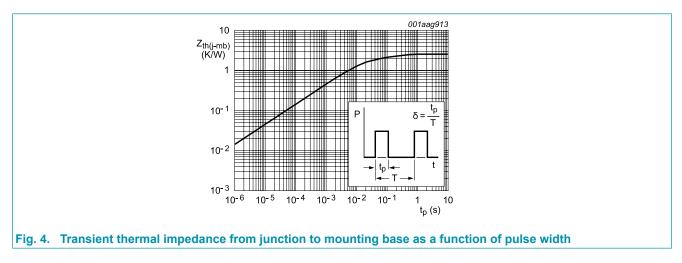
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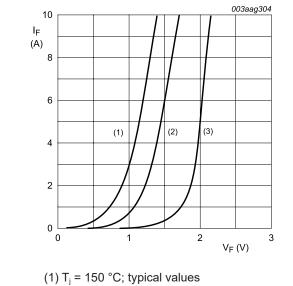
### 9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	Fig 4	-	-	2.5	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



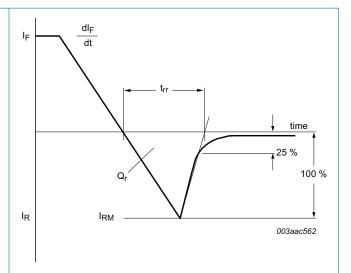
### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		Conditions	IVIIII	тур	IVIAX	Unit
Static cha	aracteristics					
V <sub>F</sub>	forward voltage $I_F = 10A; T_j = 150 \text{ °C}; Fig. 5$		-	1.4	1.7	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.5	2	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>	-	1.15	1.45	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 500 V	-	9	40	μA
		V <sub>R</sub> = 500 V; T <sub>j</sub> = 100 °C	-	0.9	3	mA
Dynamic	characteristics	· · ·				
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 6}}{6}$	-	15	30	ns
		$I_{F} = 5 \text{ A}; V_{R} = 400 \text{ V}; \text{ d}I_{F}/\text{d}t = 500 \text{ A}/\mu\text{s}; T_{j} = 25 \text{ °C}; \frac{\text{Fig. 6}}{6}$	-	16	-	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 5 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ $T_j = 125 ^\circ\text{C}; \text{ Fig. 6}$	-	0.9	3	A
		$I_F = 5 \text{ A}; V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ $T_j = 100 ^\circ\text{C}; \text{ Fig. 6}$	-	9.5	11	A
$V_{FR}$	forward recovery voltage	$I_F = 5 \text{ A}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s};$ $T_i = 25 \text{ °C}; \frac{\text{Fig. 7}}{2}$	-	9	11	V



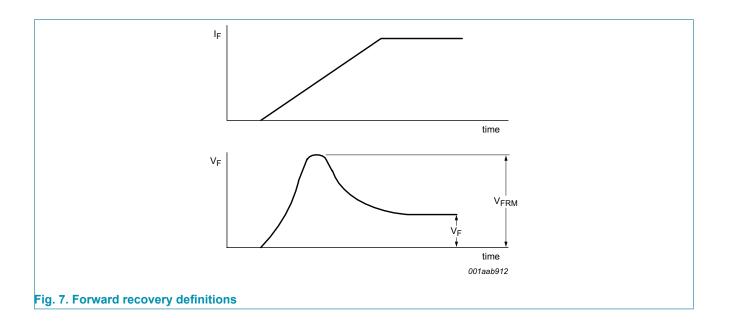
(1)  $I_j = 150$  °C; typical values (2)  $T_j = 150$  °C; maximum values (3)  $T_j = 25$  °C; maximum values  $V_o = 1.141$  V;  $R_s = 0.057 \Omega$ 

Fig. 5. Forward current as a function of forward voltage

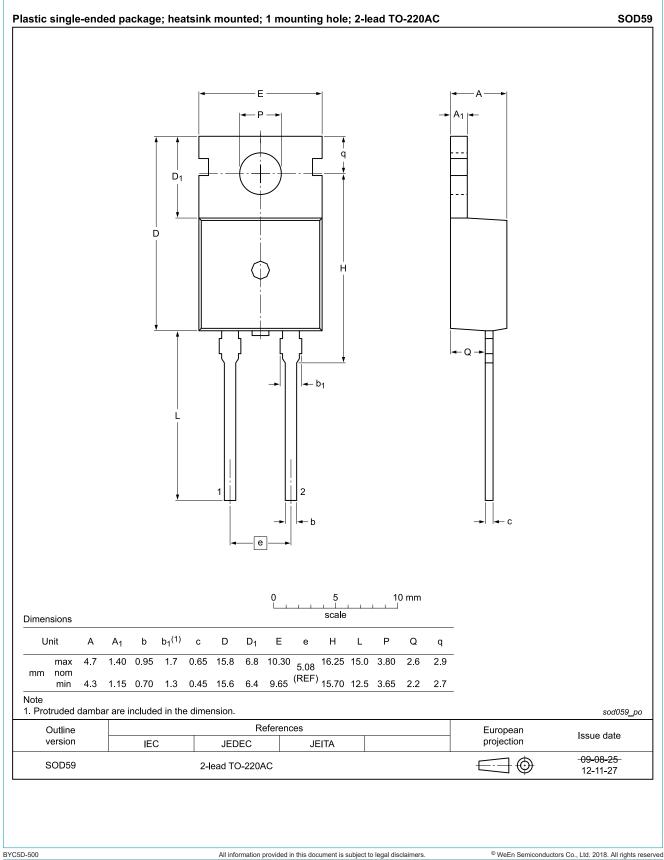




BYC5D-500 Product data sheet



### 11. Package outline



## 12. Revision history

### Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BYC5D-500 v.2	20180305	Product data sheet	-	BYC5D-500 v.1			
Modifications:	Modifications: Change from NXP version to WeEn version						
BYC5D-500 v.1	20110706	Product data sheet	-	-			

# BYC5D-500

### Hyperfast power diode

## 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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